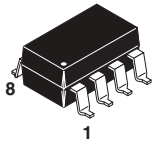
FAIRCHILD
SEMICONDUCTOR®

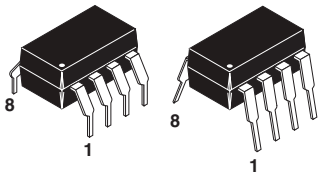
DUAL PHOTOTRANSISTOR OPTOCOUPLERS

MCT6 MCT61 MCT62

DESCRIPTION

The MCT6X Optocouplers have two channels for density applications. For four channel applications, two-packages fit into a standard 16-pin DIP socket. Each channel is an NPN silicon planar phototransistor optically coupled to a gallium arsenide infrared emitting diode.





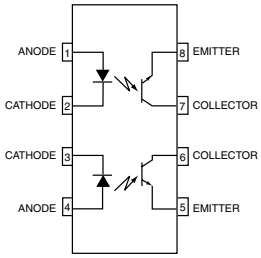
FEATURES

- Two isolated channels per package
- Two packages fit into a 16 lead DIP socket
- Choice of three current transfer ratios
- Underwriters Laboratory (U.L.) recognized File E90700

APPLICATIONS

- AC Line/Digital Logic - isolate high voltage transients
- Digital Logic/Digital Logic - Eliminate spurious grounds
- Digital Logic/AC Triac Control - isolate high voltage transients
- Twisted pair line receiver - Eliminate ground loop feedthrough
- Telephone/Telegraph line receiver - isolate high voltage transients
- High Frequency Power Supply Feedback Control - Maintain floating grounds and transients
- Relay contact monitor - isolate floating grounds and transients
- Power supply monitor - Isolate transients

SCHEMATIC



Equivalent Circuit

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
EMITTER (Each channel)			
Forward Current - Continuous	I_F	60	mA
Forward Current - Peak (PW = 1µs, 300pps)	I_F(pk)	3	A
Reverse Voltage	V_R	3.0	V
LED Power Dissipation @ T_A = 25°C Derate above 25°C (Total Input)	P_D	100 1.3	mW mW/°C
DETECTOR (Each channel)			
Collector Current - Continuous	I_C	30	mA
Detector Power Dissipation @ T_A = 25°C Derate above 25°C	P_D	150 2.0	mW mW/°C
TOTAL DEVICE			
Storage Temperature	T_{STG}	-55 to +150	°C
Operating Temperature	T_{OPR}	-55 to +100	°C
Lead Solder Temperature (wave solder)	T_{SOL}	250 for 10 sec	°C
Total Device Power Dissipation @ T_A = 25°C Derate above 25°C	P_D	400 5.33	mW mW/°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Min	Typ**	Max	Unit
EMITTER						
Input Forward Voltage	(I_F = 20 mA)	V_F		1.2	1.5	V
Reverse Voltage	(I_R = 10 µA)	V_R	3.0	25		V
Reverse Current	(V_R = 5 V)	I_R		0.001	10	µA
Junction Capacitance	(V_F = 0 V, f = 1 MHz)	C_J		50		pF
DETECTOR						
Collector-Emitter Breakdown Voltage	(I_C = 1.0 mA, I_F = 0)	BV_{CEO}	30	85		V
Emitter-Collector Breakdown Voltage	(I_E = 100 µA, I_F = 0)	BV_{ECO}	6	13		V
Collector-Emitter Dark Current	(V_{CE} = 10 V, I_F = 0)	I_{CEO}		5	100	nA
Capacitance	(V_{CE} = 0 V, f = 1 MHz)	C_{CE}		8		pF

TRANSFER CHARACTERISTICS

AC Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
SWITCHING TIMES						
Non-Saturated Turn-on Time	(R_L = 100 Ω, I_C = 2 mA, V_{CC} = 10 V)	t_{on}		2.4		µs
Non-Saturated Turn-off Time	(R_L = 100 Ω, I_C = 2 mA, V_{CC} = 10 V)	t_{off}		2.4		µs

TRANSFER CHARACTERISTICS

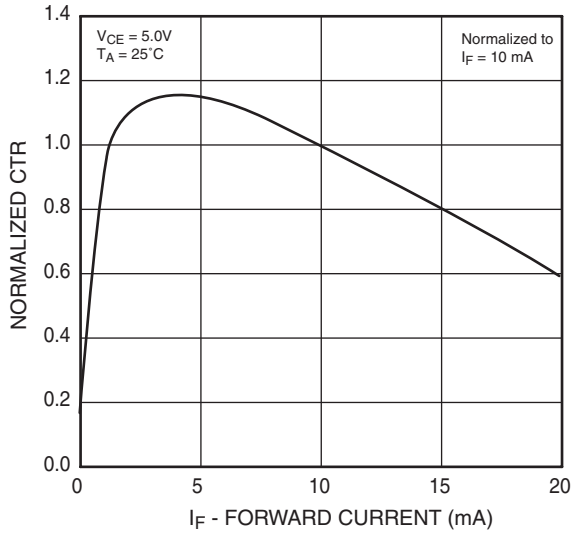
DC Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
Current Transfer Ratio, Collector-Emitter						
MCT6	(I_F = 10 mA, V_{CE} = 10 V)	CTR	20			%
MCT61	(I_F = 5 mA, V_{CE} = 5 V)		50			
MCT62			100			
Saturation Voltage	(I_F = 16 mA, I_C = 2 mA)	$V_{CE(sat)}$		0.15	0.40	V

ISOLATION CHARACTERISTICS

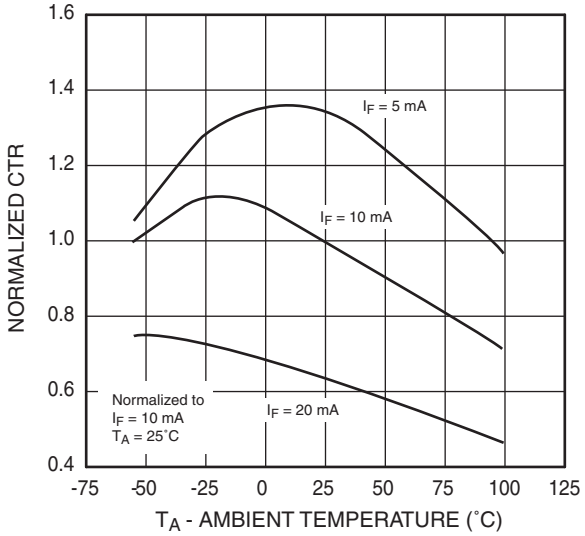
Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
Input-Output Isolation Voltage	(I_{I-O} ≤ 1 µA, t = 1 min.)	V_{ISO}	5300			Vac(rms)
Isolation Resistance	(V_{I-O} = 500 VDC)	R_{ISO}	10^{11}			Ω
Isolation Capacitance	(f = 1 MHz)	C_{ISO}		0.5		pf

** All typicals at TA = 25°C

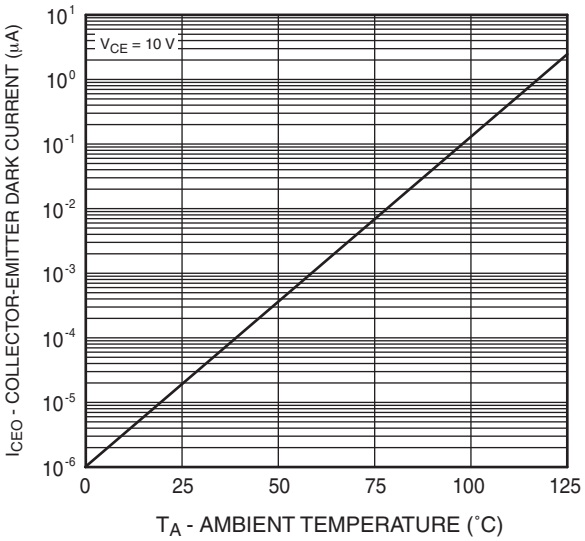
Normalized CTR vs. Forward Current



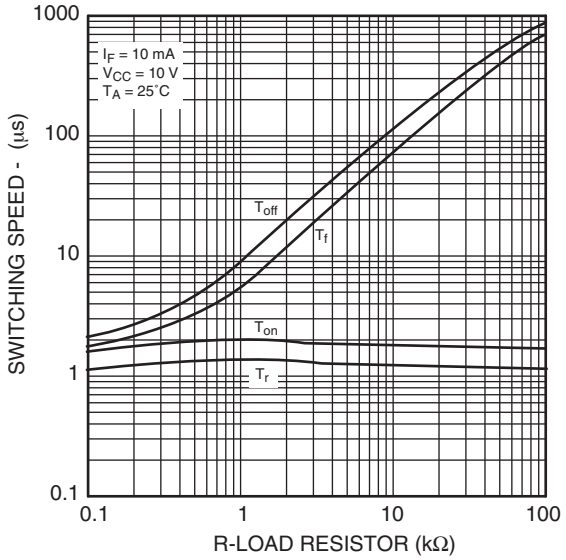
Normalized CTR vs. Ambient Temperature



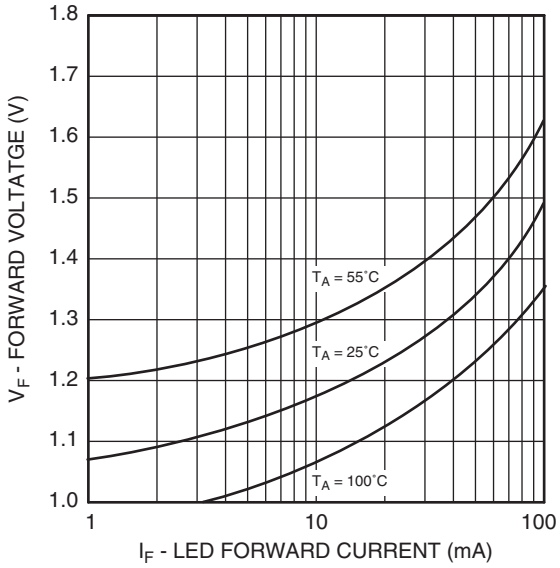
Dark Current vs. Ambient Temperature



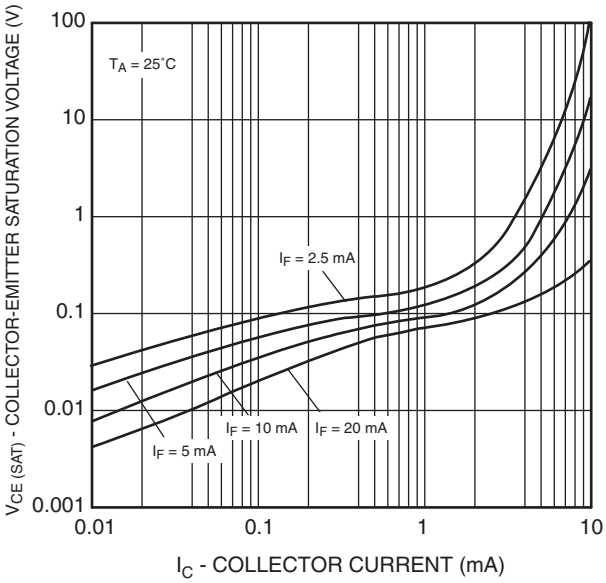
Switching Speed vs. Load Resistor



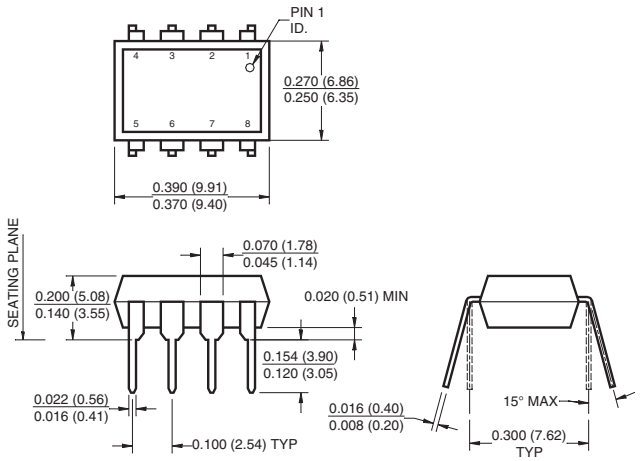
LED Forward Voltage vs. Forward Current



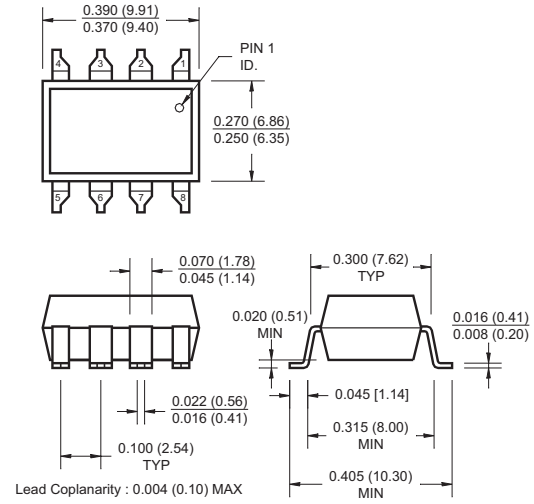
Collector-Emitter Saturation Voltage vs Collector Current



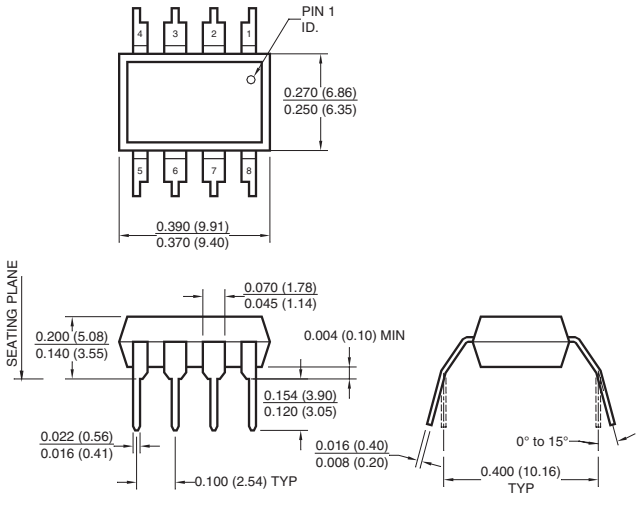
Package Dimensions (Through Hole)



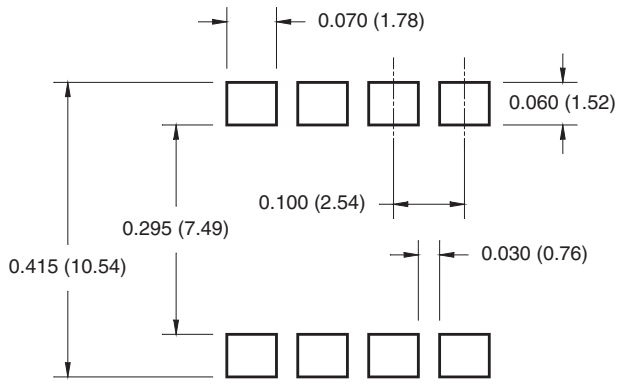
Package Dimensions (Surface Mount)



Package Dimensions (0.4"Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform

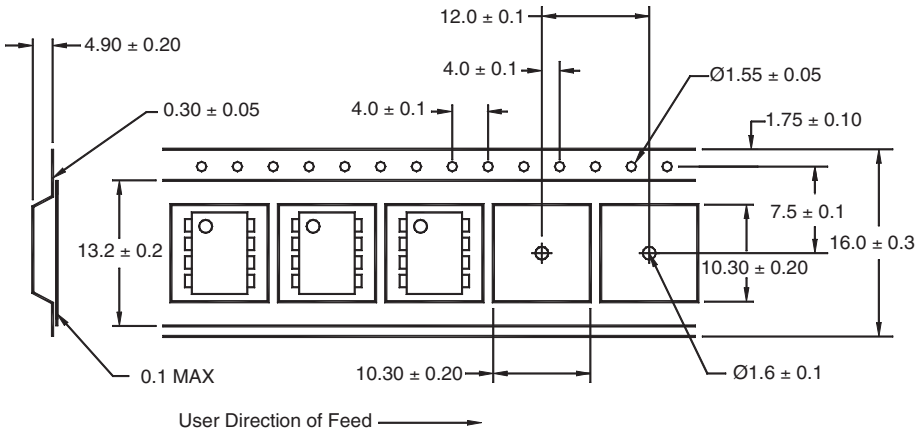


NOTE
All dimensions are in inches (millimeters)

ORDERING INFORMATION

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4” Lead Spacing

Carrier Tape Specifications



NOTE
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